### **NTA4015N**

## **Small Signal MOSFET**

# 20 V, 238 mA, Single, N-Channel, Gate ESD Protection, SC-75

#### **Features**

- Low Gate Charge for Fast Switching
- Small 1.6 x 1.6 mm Footprint
- ESD Protected Gate
- These Devices are Pb-Free and are RoHS Compliant

### **Applications**

- Power Management Load Switch
- Level Shift
- Portable Applications such as Cell Phones, Media Players,
   Digital Cameras, PDA's, Video Games, Hand Held Computers, etc.

### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise stated)

| Parameter   |                     | Symbol                               | Value         | Unit |
|---|---------------------|--------------------------------------|---------------|------|
| Drain-to-Source Voltage   |                     | $V_{DSS}$                            | 20            | V    |
| Gate-to-Source Voltage  |                     | V <sub>GS</sub>                      | ±10           | V    |
| Continuous Drain<br>Current (Note 1)                              | Steady State = 25°C | I <sub>D</sub>                       | 238           | mA   |
| Power Dissipation (Note 1) Steady State = 25°C                    |                     | P <sub>D</sub>                       | 300           | mW   |
| Pulsed Drain Current $t_P \le 10 \mu s$                           |                     | I <sub>DM</sub>                      | 714           | mA   |
| Operating Junction and Storage Temperature                        |                     | T <sub>J</sub> ,<br>T <sub>STG</sub> | -55 to<br>150 | °C   |
| Continuous Source Current (Body Diode)                            |                     | I <sub>SD</sub>                      | 238           | mA   |
| Lead Temperature for Soldering Purposes (1/8" from case for 10 s) |                     | T <sub>L</sub>                       | 260           | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### THERMAL RESISTANCE RATINGS

| Parameter                                   | Symbol          | Max | Unit |
|---|-----------------|-----|------|
| Junction-to-Ambient - Steady State (Note 1) | $R_{\theta JA}$ | 416 | °C/W |

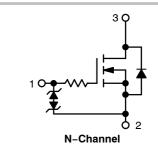
Surface-mounted on FR4 board using 1 in sq. pad size (Cu area = 1.127 in sq. [1 oz] including traces).



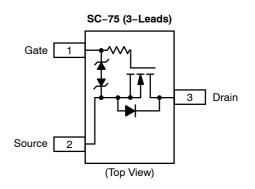
### ON Semiconductor®

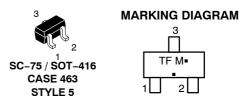
### http://onsemi.com

| V <sub>(BR)DSS</sub> | R <sub>DS(on)</sub><br>Typ @ V <sub>GS</sub> | I <sub>D</sub> MAX<br>(Note 1) |
|----------------------|--|--------------------------------|
| 20 V                 | 1.5 Ω @ 4.5 V                                | 238 mA                         |
|                      | 2.2 Ω @ 2.5 V                                | 255 117 (                      |



### **PIN CONNECTIONS**





TF = Specific Device Code

M = Date Code■ Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = 25°C unless otherwise specified)

| Parameter                          | Symbol               | Test Condition   | Min | Тур  | Max  | Unit |
|------------------------------------|----------------------|--|-----|------|------|------|
| OFF CHARACTERISTICS                |                      |  |     |      |      |      |
| Drain-to-Source Breakdown Voltage  | V <sub>(BR)DSS</sub> | $V_{GS} = 0 \text{ V}, I_D = 100 \mu\text{A}$                      | 20  |      |      | V    |
| Zero Gate Voltage Drain Current    | I <sub>DSS</sub>     | V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 20 V                      |     |      | 1.0  | μΑ   |
| Gate-to-Source Leakage Current     | I <sub>GSS</sub>     | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±10 V                     |     |      | ±100 | μΑ   |
| ON CHARACTERISTICS (Note 2)        |                      |  |     |      |      |      |
| Gate Threshold Voltage             | V <sub>GS(TH)</sub>  | $V_{DS} = 3 \text{ V}, I_{D} = 100 \mu\text{A}$                    | 0.5 | 1.0  | 1.5  | V    |
| Drain-to-Source On Resistance      | R <sub>DS(on)</sub>  | V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10 mA                    |     | 1.5  | 3.0  |      |
|                                    |                      | V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 10 mA                    |     | 2.2  | 3.5  | Ω    |
| Forward Transconductance           | 9FS                  | $V_{DS} = 3 \text{ V}, I_{D} = 10 \text{ mA}$                      |     | 80   |      | mS   |
| CAPACITANCES                       |                      |  |     |      |      |      |
| Input Capacitance                  | C <sub>ISS</sub>     |  |     | 11.5 | 20   |      |
| Output Capacitance                 | C <sub>OSS</sub>     | $V_{DS} = 5 \text{ V, f} = 1 \text{ MHz,} $ $V_{GS} = 0 \text{ V}$ |     | 10   | 15   | pF   |
| Reverse Transfer Capacitance       | C <sub>RSS</sub>     | 193 - 1  |     | 3.5  | 6.0  |      |
| SWITCHING CHARACTERISTICS (Note 3) |                      |  |     |      |      |      |
| Turn-On Delay Time                 | t <sub>d(ON)</sub>   |  |     | 13   |      | ns   |
| Rise Time                          | t <sub>r</sub>       | V <sub>GS</sub> = 4.5 V, V <sub>DS</sub> = 5 V,                    |     | 15   |      |      |
| Turn-Off Delay Time                | t <sub>d(OFF)</sub>  | $I_D = 10 \text{ mA}, R_G = 10 \Omega$                             |     | 98   |      | ns   |
| Fall Time                          | t <sub>f</sub>       |  |     | 60   |      | 1    |
| DRAIN-SOURCE DIODE CHARACTERISTICS | •                    |  | •   | •    | •    | •    |
| Forward Diode Voltage              | $V_{SD}$             | $V_{GS} = 0 \text{ V}, I_{S} = 10 \text{ mA}$                      |     | 0.66 | 8.0  | V    |
|                                    | •                    |  | -   | -    | -    |      |

Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

### NTA4015N

### TYPICAL PERFORMANCE CURVES

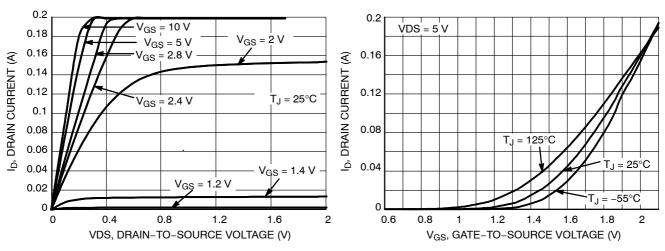


Figure 1. On-region Characteristics

Figure 2. Transfer Characteristics

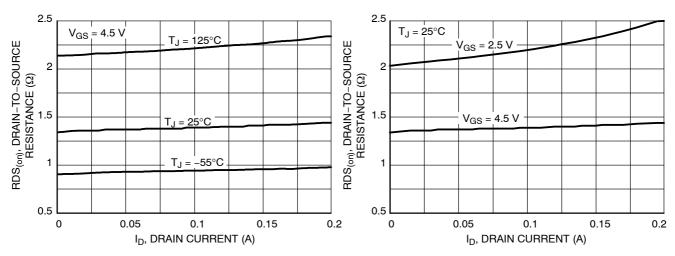


Figure 3. On-resistance versus Drain Current and Temperature

Figure 4. On-resistance versus Drain Current and Gate Voltage

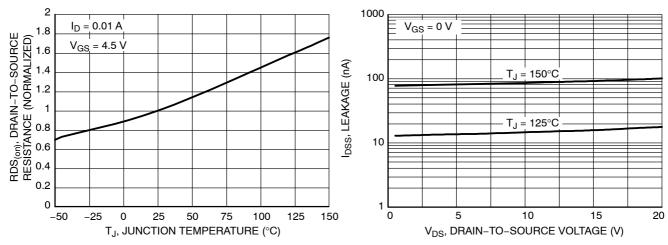
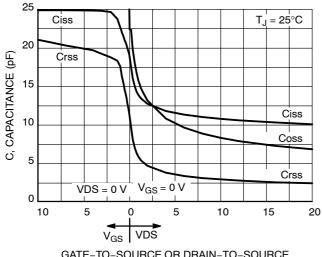


Figure 5. On–resistance Variation with Temperature

Figure 6. Drain-to-Source Leakage Current versus Voltage

### NTA4015N

### **TYPICAL PERFORMANCE CURVES**



1000  $V_{DD} = 5 V$   $V_{CS} = 4.5 V$  V

GATE-TO-SOURCE OR DRAIN-TO-SOURCE VOLTAGE (V)

Figure 8. Resistive Switching Time Variation versus Gate Resistance

Figure 7. Capacitance Variation

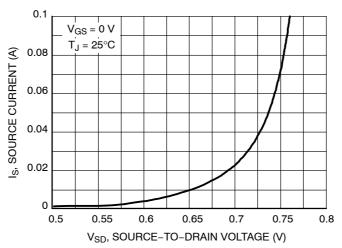


Figure 9. Diode Forward Voltage versus Current

### ORDERING INFORMATION

| Order Number | Package            | Shipping <sup>†</sup> |
|--------------|--------------------|-----------------------|
| NTA4015NT1G  | SC-75<br>(Pb-Free) | 3000 / Tape & Reel    |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



### SC75-3 1.60x0.80x0.80, 1.00P **CASE 463 ISSUE H**

**DATE 01 FEB 2024** 

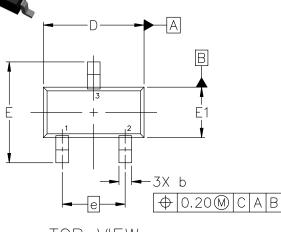
### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.

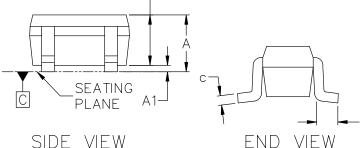
| DIM   | MILLIMETERS |      |      |  |
|-------|-------------|------|------|--|
| ואווט | MIN.        | NOM. | MAX. |  |
| А     | 0.70        | 0.80 | 0.90 |  |
| A1    | 0.00        | 0.05 | 0.10 |  |
| A2    | 0.80 REF.   |      |      |  |
| b     | 0.15        | 0.20 | 0.30 |  |
| С     | 0.10        | 0.15 | 0.25 |  |
| D     | 1.55        | 1.60 | 1.65 |  |
| E     | 1.50        | 1.60 | 1.70 |  |
| E1    | 0.70        | 0.80 | 0.90 |  |
| е     | 1.00 BSC    |      |      |  |
| L     | 0.10        | 0.15 | 0.20 |  |
|       |             |      |      |  |

0.356

0.787



VIEW



A2

SIDE VIEW

### **GENERIC MARKING DIAGRAM\***



XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. BASE 2. EMITTER

STYLE 2: PIN 1. ANODE 2. N/C 3. COLLECTOR 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

1.000

RECOMMENDED MOUNTING FOOTPRINT\*

1.803

0.508

| STYLE 4:       | STYLE 5:    |
|----------------|-------------|
| PIN 1. CATHODE | PIN 1. GATE |
| 2. CATHODE     | 2. SOURCE   |
| 3 ANODE        | 3 DRAIN     |

**DOCUMENT NUMBER:** 

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**DESCRIPTION:** SC75-3 1.60x0.80x0.80, 1.00P

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**PAGE 1 OF 1** 

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